CMOS Digital Integrated Circuits Silicon Monolithic

TC7USB42MU

1. Functional Description

Dual SPDT USB Switch

2. General

The TC7USB42MU is high-speed CMOS dual 1-2 multiplexer/demultiplexer. The low ON-resistance and the low capacitance of the switch allow connections to USB2.0 (480Mbps) application.

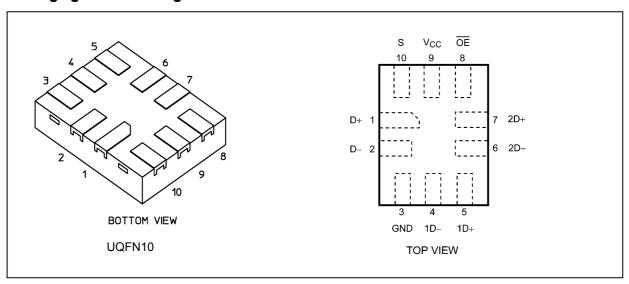
This device consists of dual individual two-inputs multiplexer/demultiplexer with common select input (S) and output enable (\overline{OE}) . The D+/D- inputs is connected to the 1D+/1D- or 2D+/2D- outputs determined by the combination both the select input (S) and output enable (\overline{OE}) . When the output enable (\overline{OE}) input is held high level, the switches are open with regardless the state of select inputs and a high-impedance state exists between the switches.

All inputs are equipped with protection circuits against static discharge.

3. Features

- (1) Supply voltage: $V_{CC} = 2.3 \text{ to } 4.3 \text{ V}$
- (2) Switch terminal ON-capacitance: $C_{I/O} = 5$ pF Switch ON (typ.) @ $V_{CC} = 3.3$ V
- (3) ON-resistance: $R_{ON} = 4.5 \Omega$ (typ.) @ $V_{CC} = 3 V$, $V_{IS} = 0 V$
- (4) R_{ON} flatness: $R_{ON(flat)} = 1.3 \Omega$ (typ.)@ $V_{CC} = 3 V$
- (5) Difference of ON-resistance between switches: $\Delta R_{ON} = 0.35 \Omega$ (typ.)@ $V_{CC} = 3 V$
- (6) ESD performance: Machine model ≥ ±200 V, Human body model ≥ ±8000 V
- (7) Power-down protection provided on all inputs and outputs.
- (8) Ultra-small Package: UQFN10

4. Packaging and Pin Assignment





5. Marking

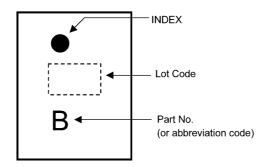


Fig. 5.1 Marking (Top view)

6. Block Diagram

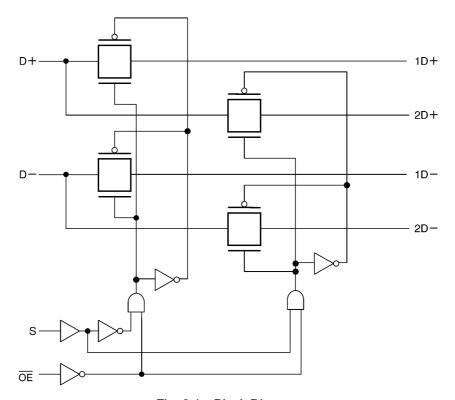


Fig. 6.1 Block Diagram

7. Principle of Operation

7.1. Truth Table

Input OE	Input S	Function				
L	L	D+ port = 1D+ port, D- Port = 1D- Port				
L	Н	D+ port = 2D+ port, D- Port = 2D- Port				
Н	Х	Disconnect				

X: Don't care



8. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Test Condition	Rating	Unit
Supply voltage	V _{CC}		_	-0.5 to 4.6	V
Input voltage (OE, S)	V _{IN}			-0.5 to 4.6	
Switch I/O voltage	Vs		V _{CC} = 0 V or Switch OFF	-0.5 to 4.6	
			Switch ON	0.5 to V _{CC} +0.5	
Clamp diode current	I _{IK}		Control input	-50	mA
			Switch	±50	
Switch I/O current	Is		_	50	
Power dissipation	P _D			200	
V _{CC} /ground current	I _{CC} /I _{GND}			±100	mA
Storage temperature	T _{stg}			-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

9. Operating Ranges (Note)

Characteristics	Symbol	Note	Test Condition Rating		Unit
Supply voltage	V _{CC}		_	2.3 to 4.3	V
Input voltage (OE, S)	V _{IN}			0 to 4.3	
Switch I/O voltage	Vs		V _{CC} = 0 V or Switch OFF	0 to 4.3	
			Switch ON	0 to V _{CC}	
Operating temperature	T _{opr}		_	-40 to 85	°C
Input rise time	dt/dv			0 to 10	ns/V
Input fall time				0 to 10	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs and bus inputs must be tied to either V_{CC} or GND.



10. Electrical Characteristics

10.1. DC Characteristics (Note) (Unless otherwise specified, T_a = -40 to 85°C)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage (OE, S)	V _{IH}		_	2.3 to 3.0	0.50 × V _{CC}		_	V
				3.0 to 4.3	0.46 × V _{CC}	l		
Low-level input voltage (OE, S)	V _{IL}			2.3 to 4.3	_		0.25 × V _{CC}	
Input leakage current (OE, S)	I _{IN}		V _{IN} = 0 to 4.3 V	2.3 to 4.3	_	1	±1	μА
Power-OFF leakage current	I _{OFF}		V _{IN} = V _{IS} = 0 to 4.3 V, See Fig. 11.10	0	_		±2	
Switch OFF-state leakage current	I _{SZ}		V_{IS} = 0 to 3.6 V, \overline{OE} = V_{CC} , See Fig. 11.11	2.3 to 4.3	_	1	±2	
ON-resistance	R _{ON}	(Note 1)	$V_{IS} = 0 \text{ V}, I_{IS} = 30 \text{ mA},$ See Fig. 11.9	3.0	_	4.5	6	Ω
			V_{IS} = 0.4 V, I_{IS} = 30 mA, See Fig. 11.9	3.0	_	4.8	6.7	
			V_{IS} = 3.0 V, I_{IS} = 30 mA, See Fig. 11.9	3.0	_	10	14	
Difference of ON-resistance between switches	ΔR _{ON}	(Note 1)	V _{IS} = 0.4 V, 1.0 V, I _{IS} = 30 mA	3.0	_	0.35		
ON-resistance flatness	R _{ON(flat)}	(Note 1)	V _{IS} = 0 V to 1.0 V, I _{IS} = 30 mA	3.0	_	1.3	_	
Quiescent supply current	I _{CC}	_	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$ A	4.3	_	_	1	μА
	ΔI_{CC}		V _{IN} = 2.6 V (one input)	4.3	_	_	40	

Note: All typical values are at $T_a = 25$ °C.

Note 1: Measured by the voltage drop between D+/D- and 1D+/1D-,2D+/2D- pins at the indicated current through the switch. On-resistance is determined by the lower of the voltages on the two pins.

10.2. AC Characteristics (Note) (Unless otherwise specified, $T_a = -40$ to 85°C)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Min	Тур.	Max	Unit
Propagation delay time	t _{PLH} / t _{PHL}	(Note 1)	C _L = 5 pF, See Fig. 11.1	3.3 ± 0.3		0.25		ns
Turn-ON time (S, OE to output)	t _{on}		$R_L = 50 \Omega, C_L = 5 pF,$ See Fig. 11.2			10	20	
Turn-OFF time (S, OE to output)	t _{off}					14	24	
Break before make	ТВВМ		$R_L = 50 \Omega, C_L = 5 pF,$ See Fig. 11.3		2		7	
Skew of opposite transitions of the same output (t _{PHL} - t _{PLH})	t _{SK(P)}	(Note 1)	C _L = 5 pF, See Fig. 11.4			0.1		
Output skew (center port to any other port)	t _{SK(O)}	(Note 1)	C _L = 5 pF, See Fig. 11.5			0.1		

Note: All typical values are at $T_a = 25$ °C. Note 1: Parameter guaranteed by design.



10.3. Analog Switch (Note) (Unless otherwise specified, T_a = -40 to 85°C)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Min	Тур.	Max	Unit
OFF isolation (non-adjacent)	OIRR		$R_T = 50 \Omega$, f = 240 MHz, See Fig. 11.6	3.3 ± 0.3	_	-24		dB
Crosstalk (non-adjacent)	Xtalk		R_T = 50 Ω , f = 240 MHz, See Fig. 11.7		_	-30	-	
-3dB Bandwidth	BW		$R_T = 50 \Omega$, $C_L = 0 pF$, See Fig. 11.8		_	1500		MHz

Note: All typical values are at $T_a = 25$ °C. Parameter guaranteed by design.

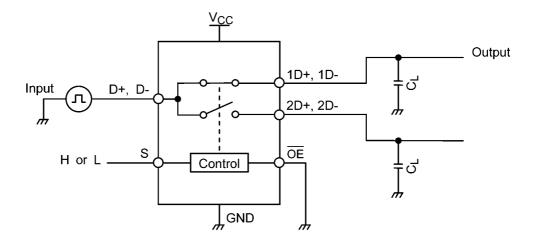
10.4. Capacitive Characteristics (Note) (Unless otherwise specified, Ta = 25°C)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance (OE, S)	C _{IN}		V _{IN} = 0 V	3.3	3	pF
Switch terminal OFF-capacitance (D+, D-)	C _{I/O}		$\overline{OE} = V_{CC}, V_{IS} = 0 V$		3	
Switch terminal OFF-capacitance (1D+, 1D-, 2D+, 2D-)					2	
Switch terminal ON-capacitance			OE = GND, V _{IS} = 0 V		5	

Note: Parameter guaranteed by design.



11. AC Test Circuits and Waveforms



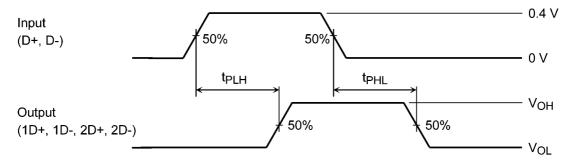
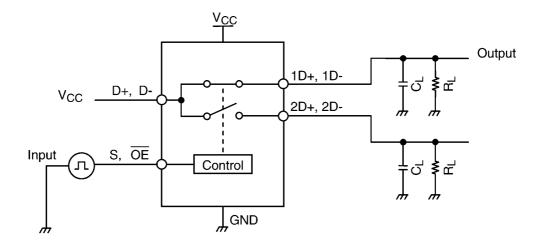


Fig. 11.1 Propagation Delay Time (t_{PLH}, t_{PHL})



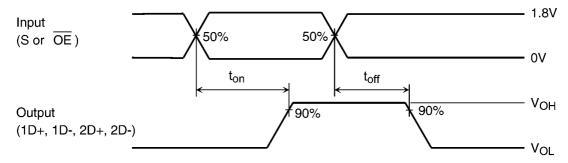


Fig. 11.2 Turn-ON and Turn-OFF Times (ton, toff)

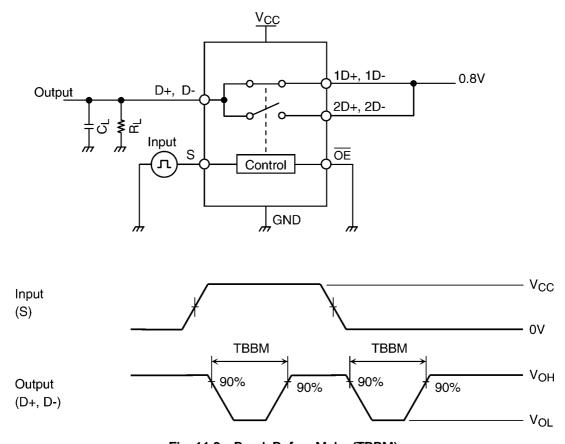
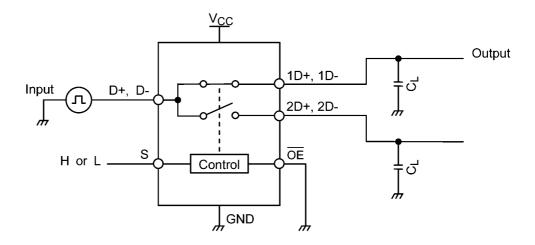


Fig. 11.3 Break Before Make (TBBM)



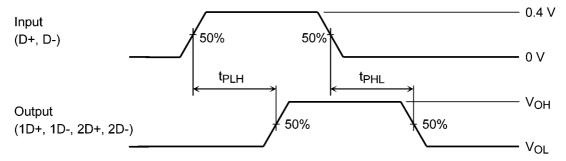


Fig. 11.4 Skew of opposite transitions of the same output $(t_{SK(P)} = |t_{PHL} - t_{PLH}|)$

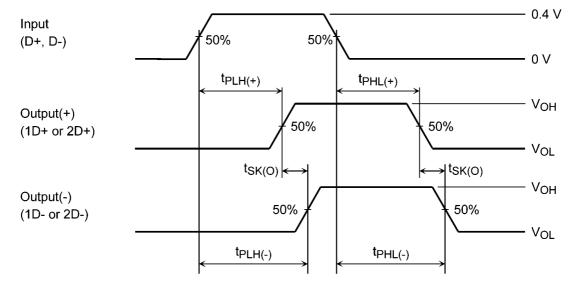


Fig. 11.5 Output Skew (center port to any other port)

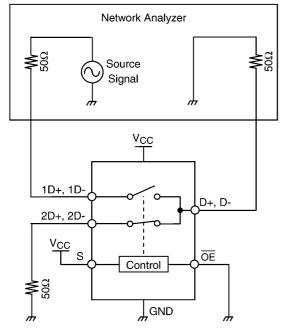


Fig. 11.6 OFF Isolation

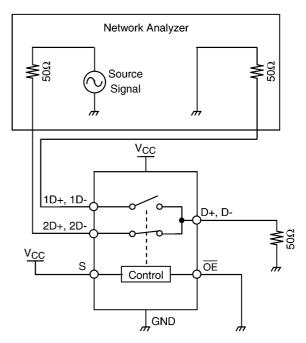


Fig. 11.7 Crosstalk

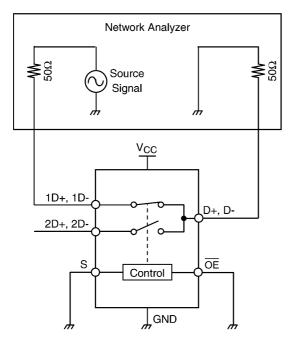


Fig. 11.8 -3dB Bandwidth

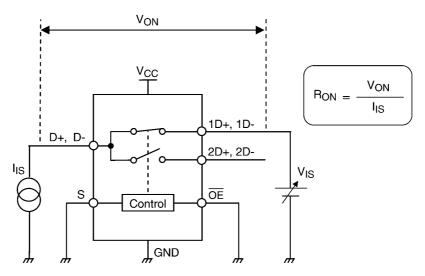


Fig. 11.9 ON-Resistance

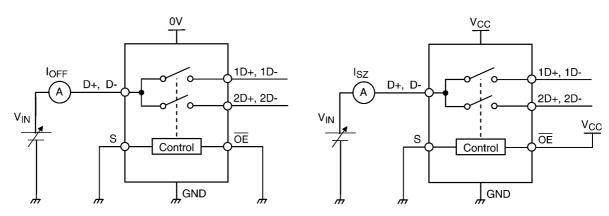


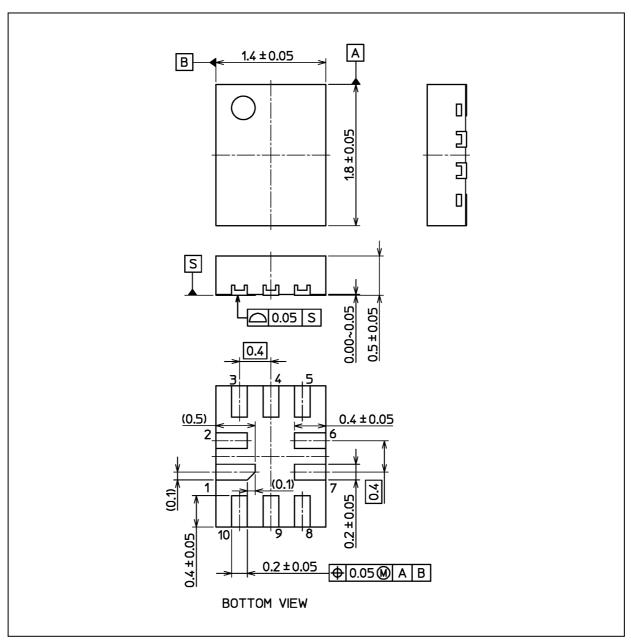
Fig. 11.10 Power-OFF Leakage Current

Fig. 11.11 Switch OFF-state leakage current



Package Dimensions

Unit: mm



This resins used in this product include no flame retardants.

Weight: 3.5 mg (typ.)

Package Name(s)
TOSHIBA: P-UQFN10-0202-0.40-001
Nickname: UQFN10



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